



#### N-CHANNEL ENHANCEMENT MODE MOSFET

## **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(ON)</sub>	I <sub>D</sub> T <sub>A</sub> = +25°C
001/	25mΩ @ V <sub>GS</sub> = 10V	6.2A
30V	$28m\Omega$ @ $V_{GS} = 4.5V$	5.8A

#### **Features and Benefits**

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Description and Applications**

This new generation MOSFET is designed to minimize the on-state resistance  $(R_{DS(ON)})$  and yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- Load Switch
- DC-DC Converters
- Power Management Functions

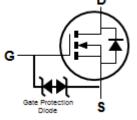
#### **Mechanical Data**

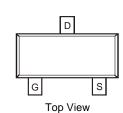
- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram (3)
- Weight: 0.009 grams (Approximate)





SOT23





Top View

Equivalent Circuit

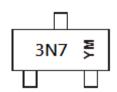
#### **Ordering Information** (Note 4)

Part Number	Case	Packaging
DMN3023L-7	SOT23	3,000/Tape & Reel
DMN3023L-13	SOT23	10,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**



3N7 = Product Type Marking Code Y or  $\overline{Y}$  = Year (ex: B = 2014) M = Month (ex: 9 = September)

Date Code Key

Year	2014	2015	2016	2017	7 201	8 20	)19	2020	2021	2022	2023	2024
Code	В	С	D	Е	F	(	G	Н	I	J	K	L
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



# **Maximum Ratings** ( $@T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Units
Drain-Source Voltage	V <sub>DSS</sub>	30	V
Gate-Source Voltage	V <sub>GSS</sub>	±20	V
Continuous Drain Current (Note 6) V <sub>GS</sub> = 10V	I <sub>D</sub>	6.2 4.9	А
Pulsed Drain Current (380µs Pulse, Duty Cycle = 1%	I <sub>DM</sub>	44	Α
Maximum Body Diode Forward Current (Note 6)	Is	1.5	Α
Avalanche Current (Note 7) L = 0.1mH	I <sub>AS</sub>	17.5	Α
Avalanche Energy (Note 7) L = 0.1mH	E <sub>AS</sub>	15.2	mJ

## **Thermal Characteristics**

Characteristic	Symbol	Value	Units		
Total Power Dissipation (Note 5)	T <sub>A</sub> = +25°C	0	0.9	W	
Total Power Dissipation (Note 5)	$T_A = +70^{\circ}C$	$P_{D}$	0.6		
Thermal Resistance, Junction to Ambient (Note 5)	Steady state	C	144	°C/W	
Thermal Resistance, Junction to Ambient (Note 5)	t<10s	$R_{\theta JA}$	103	C/VV	
Total Power Dissipation (Note 6)	$T_A = +25$ °C	ь	1.3	W	
Total Power Dissipation (Note 6)	$T_A = +70^{\circ}C$	$P_{D}$	0.8		
Thermal Resistance, Junction to Ambient (Note 6)	Steady state	C	97	°C/W	
Thermal Resistance, Junction to Ambient (Note 6)	t<10s	$R_{\theta JA}$	70		
Thermal Resistance, Junction to Case (Note 6)	$R_{ heta JC}$	24			
Operating and Storage Temperature Range	$T_{J_i} T_{STG}$	-55 to +150	°C		

# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

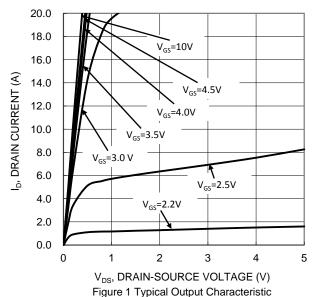
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition		
OFF CHARACTERISTICS (Note 8)								
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	30	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$		
Zero Gate Voltage Drain Current	I <sub>DSS</sub>		_	1	μΑ	V <sub>DS</sub> = 24V, V <sub>GS</sub> = 0V		
Gate-Body Leakage	I <sub>GSS</sub>	_	_	±10	μΑ	$V_{GS} = \pm 16V, V_{DS} = 0V$		
ON CHARACTERISTICS (Note 8)								
Gate Threshold Voltage	V <sub>GS(TH)</sub>	0.8		1.8	V	$V_{DS} = V_{GS}$ , $I_D = 250\mu A$		
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>		_	25 28 68	mΩ	$V_{GS} = 10V, I_D = 4.0A$ $V_{GS} = 4.5V, I_D = 3.5A$ $V_{GS} = 2.5V, I_D = 2.5A$		
Source-Drain Diode Forward Voltage	V <sub>SD</sub>	_	_	1.2	V	$V_{GS} = 0V$ , $I_S = 1A$		
DYNAMIC CHARACTERISTICS (Note 9)								
Input Capacitance	C <sub>iss</sub>		873	_	pF			
Output Capacitance	Coss		121	_	pF	$V_{DS} = 15V, V_{GS} = 0V$ f = 1.0MHz		
Reverse Transfer Capacitance	C <sub>rss</sub>		67	_	pF			
Gate Resistance	$R_g$	1	77	_	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$		
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg		18.4	_	nC			
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg	_	8.3	_	nC	V <sub>DS</sub> = 15V, I <sub>D</sub> = 4A		
Gate-Source Charge	Q <sub>gs</sub>	_	2.2	_	nC	$V_{DS} = 15V$ , $I_D = 4A$		
Gate-Drain Charge	Q <sub>gd</sub>	_	2.5	_	nC			
Turn-On Delay Time	t <sub>D(ON)</sub>	_	17	_	ns			
Turn-On Rise Time	t <sub>R</sub>		18	_	ns	V <sub>DD</sub> = 15V, V <sub>GS</sub> = 10V,		
Turn-Off Delay Time	t <sub>D(OFF)</sub>		231	_	ns $R_L = 15\Omega$ , $R_G = 6\Omega$			
Turn-Off Fall Time	t <sub>F</sub>		70	_	ns			

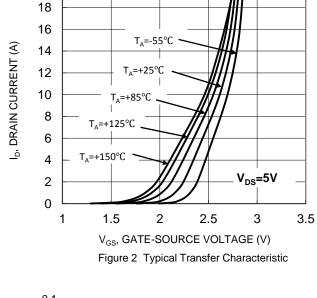
 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. Notes:

9. Guaranteed by design. Not subject to product testing.

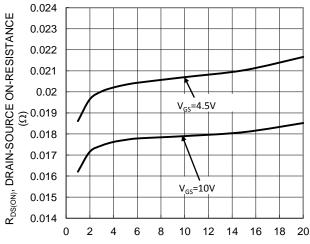
<sup>7.</sup>  $I_{AS}$  and  $E_{AS}$  rating are based on low frequency and duty cycles to keep  $T_J$  = +25°C. 8. Short duration pulse test used to minimize self-heating effect.

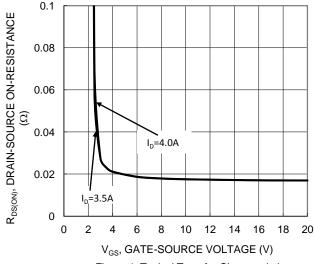






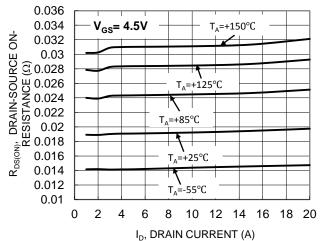
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I<sub>D</sub>, DRAIN-SOURCE CURRENT Figure 3 Typical On-Resistance vs Drain Current and Gate Voltage

Figure 4 Typical Transfer Characteristic



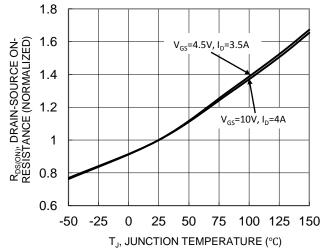


Figure 5 Typical On-Resistance vs Drain Current and Temperature

Figure 6 On-Resistance Variation with Temperature



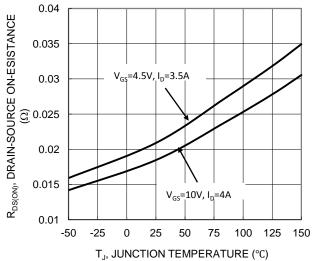
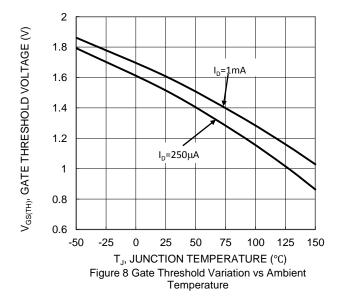


Figure 7 On-Resistance Variation with Temperature



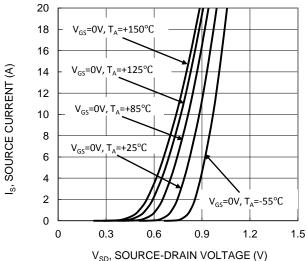
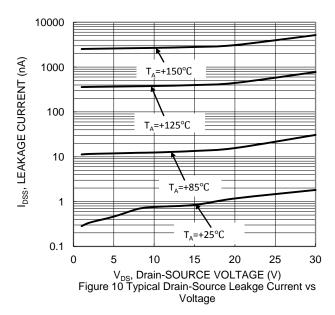
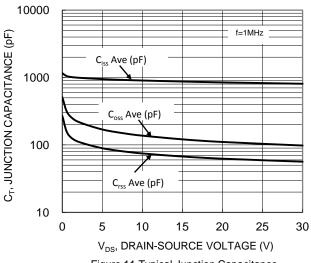
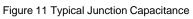
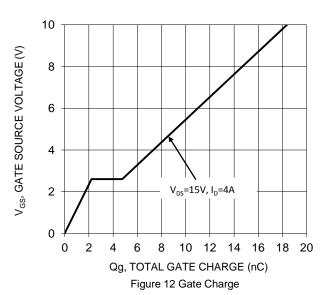


Figure 9 Diode Forward Voltage vs. Current











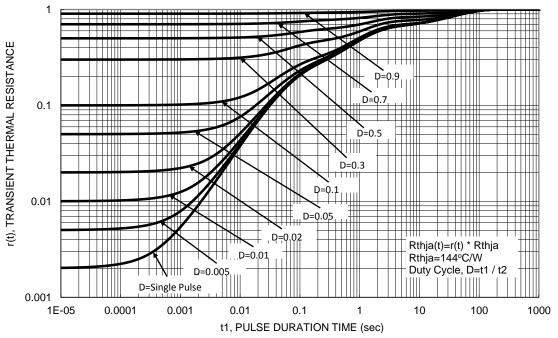
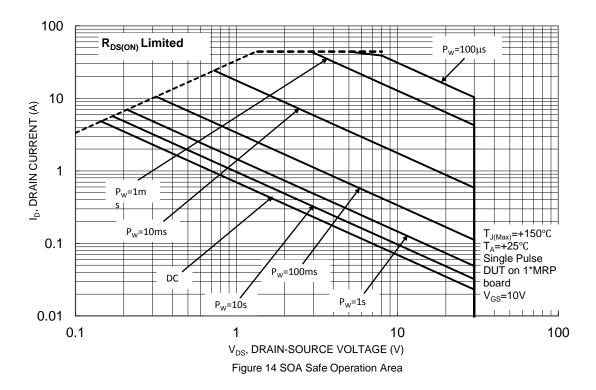


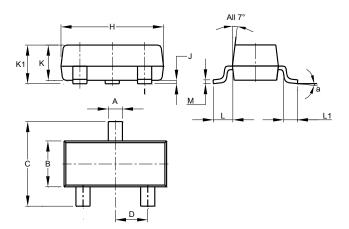
Figure 13 Transient Thermal Resistance





# **Package Outline Dimensions**

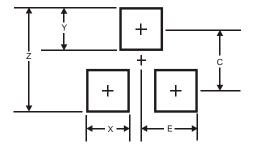
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT23							
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
С	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Н	2.80	3.00	2.90				
J	0.013	0.10	0.05				
K	0.890	1.00	0.975				
K1	0.903	1.10	1.025				
L	0.45	0.61	0.55				
L1	0.25	0.55	0.40				
М	0.085	0.150	0.110				
а	8°						
All	All Dimensions in mm						

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
E	1.35

August 2015
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